

## Multi-Mode PWM Controller of Flyback with Frequency Swapping and Integrated Protection

REV.00

### General Description

In order to enhance the efficiency performance, the LD5523U integrates the multi-mode PWM controller, which consists of Quasi-Resonant (QR) PWM control for light load condition and peak load mode for heavy load condition. Moreover, the QR controller not only gains the system performance, but also brings the worse EMI capability, while the frequency swapping function of LD5523U can reduce the EMI emission of SMPS and helps the power circuit designers to simply deal with EMI filter and saves several component and developing time.

The LD5523U is implemented in SOT-26 package, and includes the comprehensive protection function, such as Over Load Protection (OLP), Over Voltage Protection (OVP), Output Short Circuit Protection (OSCP) and internal Over Temperature Protection (OTP). Furthermore, the programmable brown-in/out protection is built-in.

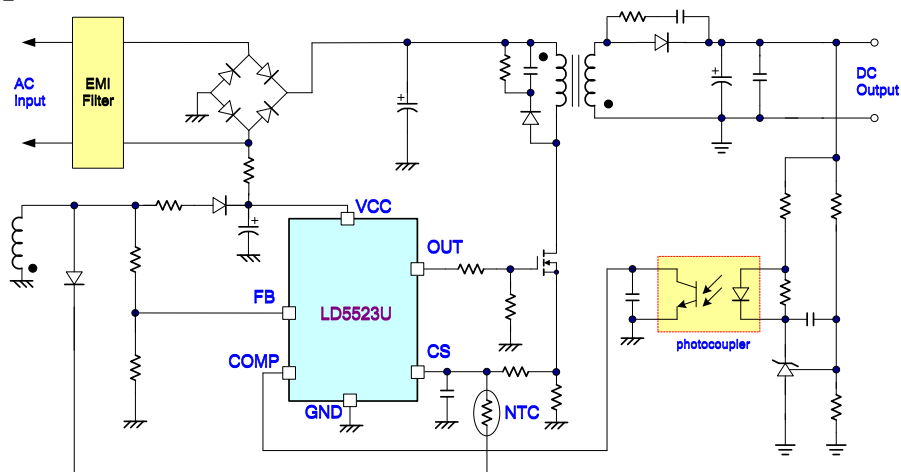
### Features

- Secondary-side feedback control with quasi-resonant + peak load mode operation
- Low Startup Current ( $<1\mu\text{A}$ )
- 0.395mA Ultra-low operating current at light load
- Current Mode Control with Cycle-by-Cycle Current Limit
- Green Mode Control
- UVLO (Under Voltage Lockout)
- LEB (Leading-Edge Blanking) on CS Pin
- VCC OVP (Over Voltage Protection)
- Adj. OVP (Over Voltage Protection) on FB pin.
- Adj. UVP (Under Voltage Protection) on FB pin.
- Adj. Brown in/out on FB pin.
- OLP (Over Load Protection)
- External OTP (Over Temperature Protection) on CS Pin
- Internal OTP (Over Temperature Protection)
- SDSP (Secondary Diode Short Protection)
- Gate Source/Sink Capability: 190mA/-310mA @ output pin with 33nF capacitor.

### Applications

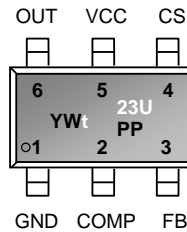
- Switching AC/DC Adaptor

### Typical Application



## Pin Configuration

SOT-26 (TOP VIEW)



Y : Year code (D: 2004, E: 2005.....)  
 W : Week code  
 PP : Production code  
 t23U : LD5523U

## Ordering Information

Part number	Package		TOP MARK	Shipping
LD5523UGL	SOT-26	(Green Package)	YWt/23U/PP	3000 /tape & reel

The LD5523U is RoHs compliant/ green packaged.

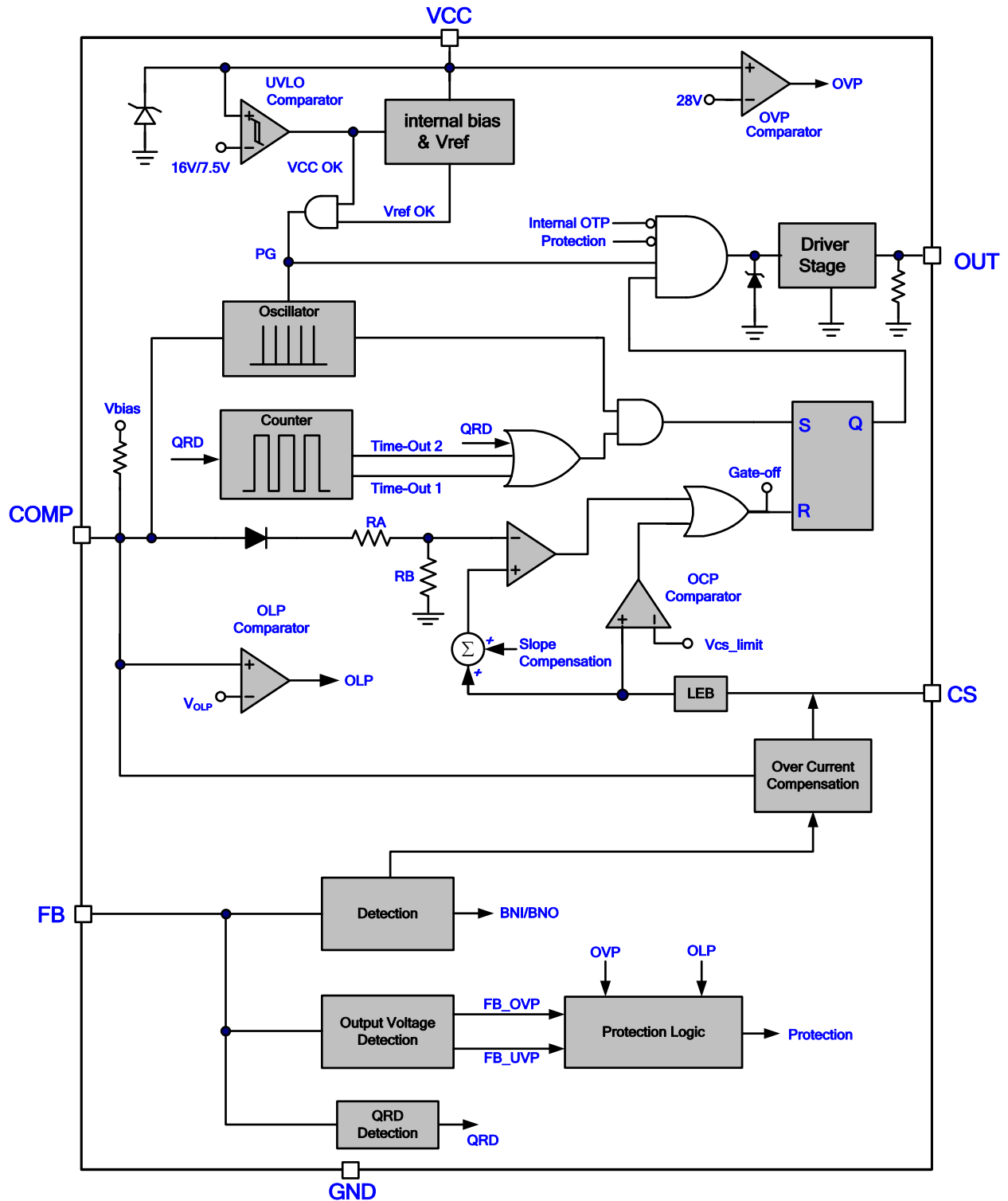
## Protection Mode

Product Name	Switching Freq.	VCC_OVP	FB_OVP	OSCP	OCP / OLP	BNI / BNO	CS_OTP	Int. OTP
LD5523U	65kHz/ 130kHz	Auto recovery	Auto recovery	Auto recovery	Auto recovery	Auto recovery	Auto recovery	Auto recovery

## Pin Descriptions

NAME	PIN (SOT-26)	FUNCTION
GND	1	Ground
COMP	2	Output of the error amplifier for voltage compensation
FB	3	Auxiliary voltage sense, brown in/out and Quasi Resonant detection
CS	4	Current sense pin, connect to sense the MOSFET current
VCC	5	Supply voltage pin
OUT	6	Gate drive output to drive the external MOSFET

## Block Diagram



## Absolute Maximum Ratings

Supply Voltage VCC.....	-0.3V ~ 30V
COMP.....	-0.3V ~ 12V
FB, CS.....	-0.3V ~ 7V
OUT.....	-0.3V ~ VCC+0.3V
Maximum Junction Temperature.....	150°C
Storage Temperature Range.....	-65°C ~ 150°C
Package Thermal Resistance (SOT-26, $\theta_{JA}$ ).....	200°C/W
Power Dissipation (SOT-26, at Ambient Temperature = 85°C).....	200mW
Lead temperature (Soldering, 10sec).....	260°C
ESD Voltage Protection, Human Body Model.....	2.5 KV
ESD Voltage Protection, Machine Model.....	250 V

### Caution:

Stress exceeding maximum ratings may damage the device. Maximum ratings are stress ratings only. Functional operation above the recommended operating conditions is not implied. Extended exposure to stress above recommended operating conditions may affect device reliability.

## Recommended Operating Conditions

Item	Min.	Max.	Unit
Operating Junction Temperature	-40	125	°C
Supply VCC Voltage	8.0	26.5	V
VCC Capacitor	3.3	10	μF
Start-up resistor Value (AC Side, Half Wave)	400K	2M	Ω
Comp Pin Capacitor (X7R type)	330	4700	pF
CS Pin Capacitor Value	47	470	pF

### Note:

1. It's essential to connect VCC pin with a SMD ceramic capacitor (0.1μF ~ 0.47μF) to filter out the undesired switching noise for stable operation. This capacitor should be placed close to IC pin as possible.
2. It's also essential to connect a capacitor to COMP to filter out the undesired switching noise for stable operation.
3. The small signal components should be placed close to IC pin as possible.

## Electrical Characteristics

(T<sub>A</sub> = +25°C unless otherwise stated, V<sub>CC</sub>=15.0V)

PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
<b>Supply Voltage (VCC Pin)</b>						
Startup Current		I <sub>CC_ST</sub>			1	μA
Operating Current (with 1nF load on OUT pin)	V <sub>COMP</sub> =0V, OUT=1nF	I <sub>CC_OP1</sub>		0.395		mA
	V <sub>COMP</sub> =1.7V, OUT=1nF I <sub>FB</sub> =200μA	I <sub>CC_OP2</sub>		2.5		mA
	Auto current protection	I <sub>CC_OPA1</sub>		0.6		mA
	Brown in (Before the first pulse)/ Brown out	I <sub>CC_OPA3</sub>		1.1		mA
UVLO(OFF)		V <sub>CC_OFF</sub>	6	7	7.8	V
UVLO(ON)		V <sub>CC_ON</sub>	15.5	16.5	17.5	V
VCC OVP Level		V <sub>CC_OVP</sub>	27	28	29	V
VCC OVP de-bounce time		T <sub>VCC_OVP</sub>		8		Cycle
<b>Voltage Feedback (COMP Pin)</b>						
Short Circuit Current	V <sub>COMP</sub> =0V	I <sub>COMP</sub>		0.227		mA
Open Loop Voltage	(1)	V <sub>COMP_OPEN</sub>		3.15		V
Min. OCP Compensation Current	I <sub>FB</sub> =100μA (1)	I <sub>OCP_MIN</sub>		162.5		μA
Max. OCP Compensation Current	I <sub>FB</sub> =300μA	I <sub>OCP_MAX</sub>		487.5		μA
<b>Current Sensing (CS Pin)</b>						
Maximum Input Voltage	(I <sub>FB</sub> < 215μA)		V <sub>CS_LIMIT_LL</sub>	0.85		V
	(I <sub>FB</sub> > 215μA)		V <sub>CS_LIMIT_HL</sub>	0.8		
OCP Voltage for Low line	Duty ≤ 50%	T <sub>J</sub> = +25°C	V <sub>CS_L</sub>	0.65		V
OCP Voltage Hysteresis for High line	Duty ≤ 20%	T <sub>J</sub> = +25°C	V <sub>CS_H_HYS</sub>	80		mV
Leading Edge Blanking Time		T <sub>LEB</sub>		275		ns
Internal Slope Compensation	*ton>3μs to D <sub>MAX</sub> . (Linearly increase), (1)		V <sub>SLP_L</sub>	440		mV
Delay to Output	(1)	T <sub>PD</sub>		80		ns

PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
<b>QRD (Quasi Resonant Detection, FB Pin)</b>						
FB OVP Trip voltage Level		$V_{FB\_OVP}$	3.3	3.5	3.7	V
FB OVP De-bounce Time		$T_{FB\_OVP}$		8		Cycle
FB UVP Trip voltage Level	(1)	$V_{FB\_UVP}$		0.8		V
QRD Trip Level	(1)	$I_{QRD}$		10		$\mu A$
<b>BNO Protection (FB Pin)</b>						
Brown In Trip Level		$I_{BNI}$	85	90	95	$\mu A$
BNO Hysteresis		$I_{BNO\_HYS}$	9	10	11	$\mu A$
Brown Out De-bounce Time	$V_{COMP}=1.7V$	$T_{DB\_BNO}$		75		ms
<b>OTP (Over Temperature, CS Pin)</b>						
CS OTP Level		$V_{CS\_OTP}$		0.75		V
CS OTP de-bounce time	(1)	$T_{CS\_OTP}$		5.4		ms
<b>Oscillator for Switching Frequency</b>						
Frequency	Normal mode	$F_{SW}$	60	65	70	kHz
	Peak mode	$F_{SW\_PK}$		130		kHz
Frequency Swapping		$F_{SW\_MOD}$		$\pm 8$		%
Green Mode Frequency		$F_{SW\_GREEN}$	21	24	27	kHz
Temp. Stability	(1)	$F_{SW\_TS}$		3	5	%
Voltage Stability	$V_{CC}=9V\sim 24V^{(1)}$	$F_{SW\_VS}$			1	%
Maximum Duty		$D_{MAX}$		81		%
<b>Gate Drive Output (OUT Pin)</b>						
Output Low Level	$V_{CC}=15V, I_o=20mA$	$V_{OL}$			1	V
Output High Level	$V_{CC}=15V, I_o=20mA$	$V_{OH}$	9		14	V
Rising Time	$V_{CC}=15V, C_L=1000pF$	$T_r$		400		ns
Falling Time	$V_{CC}=15V, C_L=1000pF$	$T_f$		75		ns
Output High Clamp Level	$V_{CC}=18V$	$V_{O\_CLAMP}$		11.5		V
<b>Soft Start</b>						
Soft Start Time	$V_{CS\_OFF}$ from 0.2V to 0.5V <sup>(1)</sup>	$T_{SS}$		7		ms
<b>SDSP (Secondary Diode Short Protection)</b>						
SDSP CS Pin Level	Secondary diode short	$V_{CS\_SDSP}$	1.2	1.5	1.8	V
De-bounce Cycle	(1)	$T_{D\_SDSP}$		4		Cycle

PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
<b>OPP (Over Power Protection)</b>						
OPP Trip Level		V <sub>COMP_OPP</sub>		2.8		V
OPP Delay Time	After soft-start	T <sub>D_OPP</sub>		60		ms
<b>OCP (Over Current Protection)</b>						
OCP Delay Time	After soft-start	T <sub>D_OCP</sub>	10	13		s
<b>On Chip OTP (Over Temperature Protection)</b>						
OTP Level	(1,2)	T <sub>INOTP</sub>		140		°C
OTP Hysteresis	(1,2)	T <sub>INOTP_HYS</sub>		12		°C

**Notes:**

1. Guaranteed by design.
2. The threshold temperature for enabling the output again and resetting the latch after OTP has been activated.

## Typical Performance Characteristics

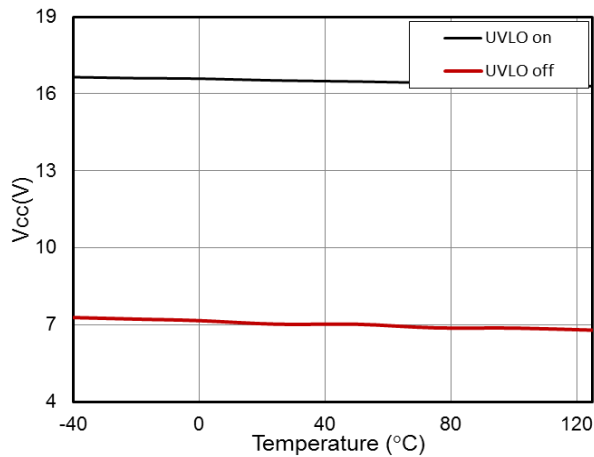


Fig. 1 UVLO Level vs. Temperature

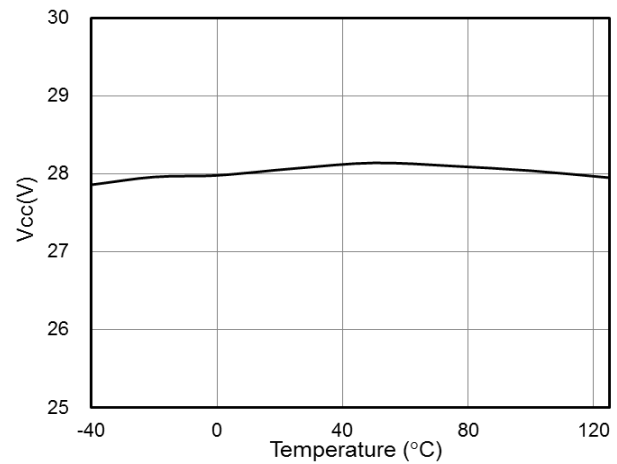


Fig. 2 Vcc OVP Level vs. Temperature

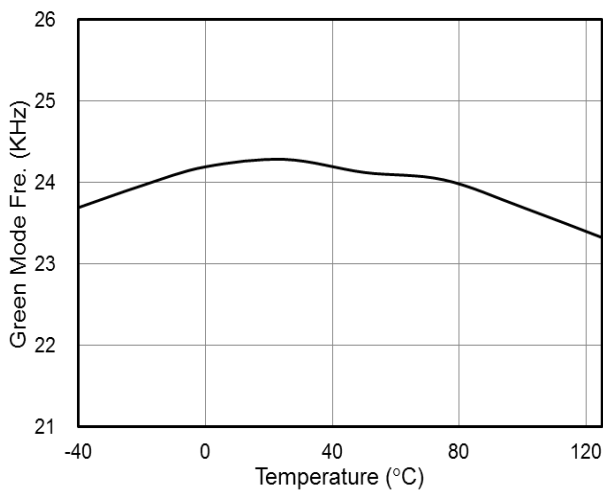


Fig. 3 Green Mode Fre. vs. Temperature

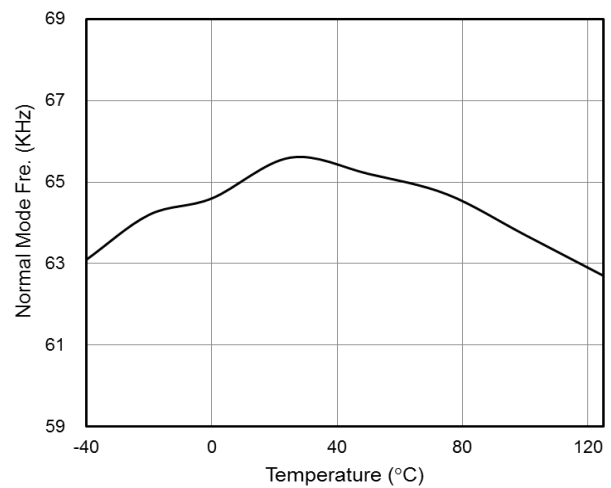


Fig. 4 Normal Mode Fre. vs. Temperature

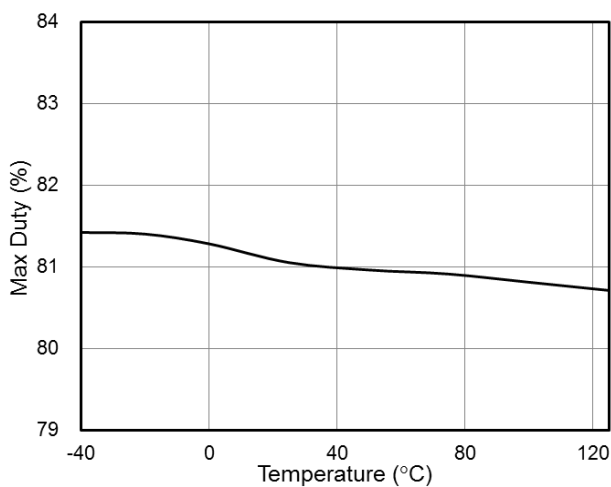


Fig. 5 Max Duty vs. Temperature

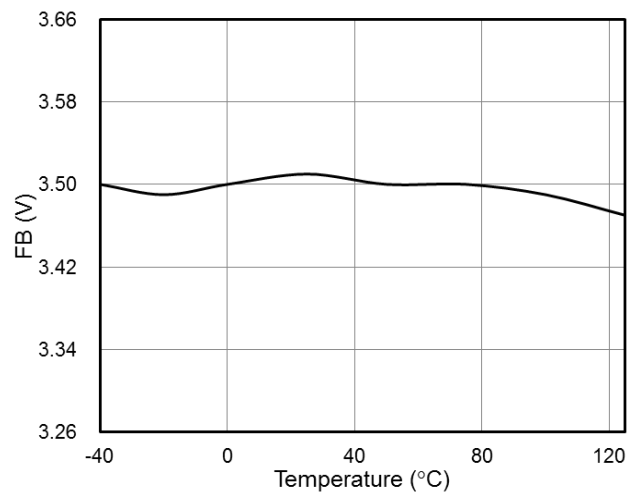


Fig. 6 FB OVP Level vs. Temperature



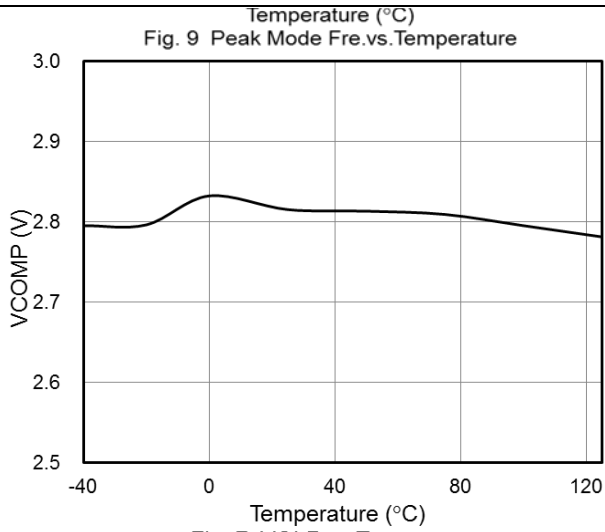


Fig. 7 VOLP vs.Temperature

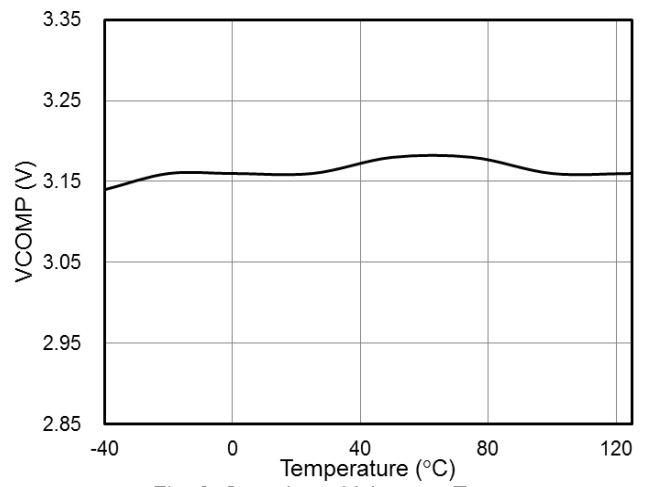


Fig. 8 Open Loop Voltage vs.Temperature

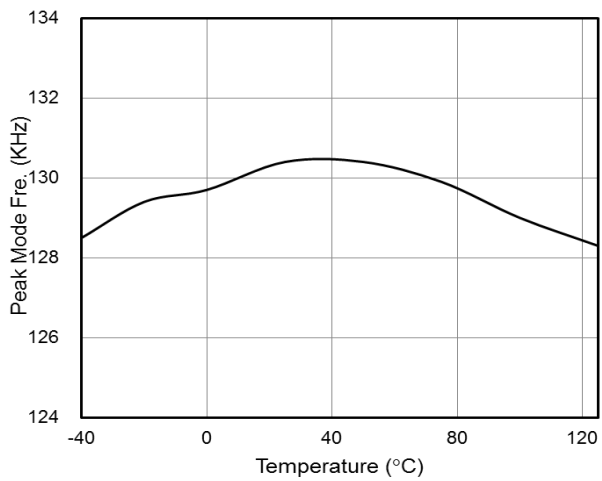


Fig. 9 Peak Mode Fre.vs.Temperature

## Application Information

### Operation Overview

The LD5523U is built in the multi-mode PWM controller, in which operates a high frequency to avoid the transformer saturation in over load condition. For demanding higher power efficiency and power-saving in light load condition, the LD5523U implements QR function to allow the valley switching and accomplish zero voltage switching (ZVS). Under different load conditions, LD5523U provides the different solutions for achieving higher efficiency and performance.

### Under Voltage Lockout (UVLO)

An UVLO comparator is implemented in it to detect the voltage on the VCC pin. It would assure the supply voltage enough to turn on the LD5523U PWM controllers and further to drive the power MOSFET. As shown in Fig. 10, a hysteresis is built in to prevent the shutdown from the voltage dip during startup. The turn-on and turn-off threshold level are set at 16.5V and 7V, respectively.

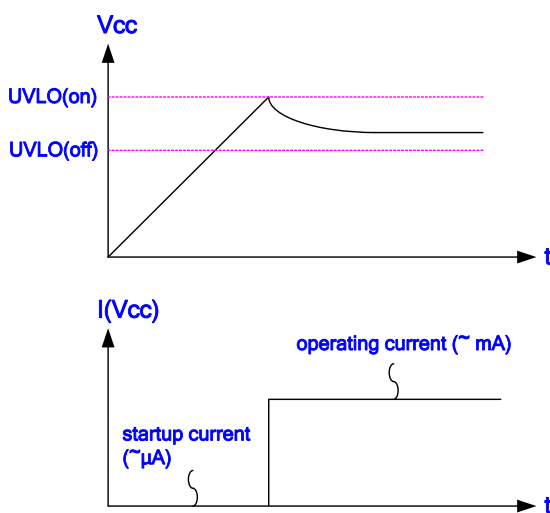


Fig. 10

### Startup Current and Startup Circuit

The typical startup circuit to generate the LD5523U VCC is shown in Fig. 11. During the startup transient, the VCC is lower than the UVLO threshold thus there is no

gate pulse produced from LD5523U to drive power MOSFET. Therefore, the current through R1 will provide the startup current and to charge the capacitor C1. Whenever the VCC voltage is high enough to turn on the LD5523U and further to deliver the gate drive signal, the supply current is provided from the auxiliary winding of the transformer.

Lower startup current requirement on the PWM controller will help to increase the value of R1 and then reduce the power consumption on R1. By using CMOS process and the special circuit design, the maximum startup current of LD5523U is only 1μA. If a higher resistance value of R1 is chosen, it usually takes more time to start up. To select the value of R1 and C1 carefully will optimize the power consumption and startup time.

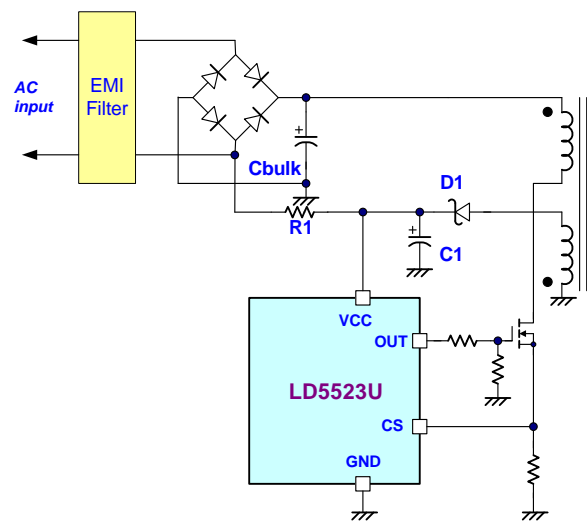


Fig. 11

### QR Mode Detection

The transformer will be demagnetized after the main power MOSFET turns off. A quasi resonant signal will be detected from auxiliary winding by FB pin through the external resistor.

As soon as the current of the secondary side diode is down to zero during MOSFET-off period, the transformer's core is demagnetized completely.  $V_{DS}$  of MOSFET will resonate in discontinuous current mode.

The resonance frequency ( $F_{QR}$ ) will be obtained as below.

$$F_{QR} = \frac{1}{2\pi\sqrt{L_m * C_R}} \text{ (HZ)}$$

$L_M$  = Inductance of primary winding

$C_R$  = Resonance equivalent parasitic capacitance

If  $V_{DS}$  voltage falls to resonant valley level from max plateau value, the QRD comparator will be tripped while FB pin current is close to  $10\mu A$ .

However, the QR detection will be influenced by propagation delay. If inductance of primary winding is less than  $500\mu H$ , there is barb in  $V_{ds}$  (as shown in Fig. 12).

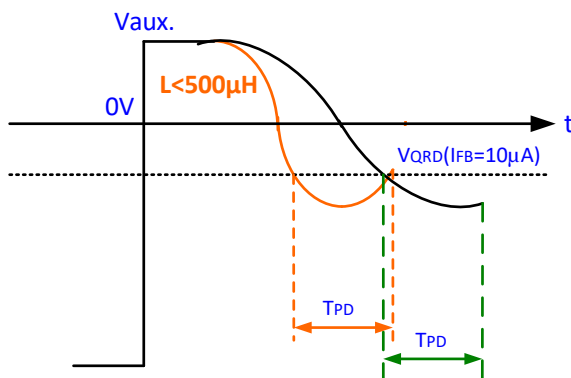


Fig. 12

## Voltage Feedback Loop

The voltage feedback signal is provided from the TL431 at the secondary side through the photo-coupler to the COMP pin of the LD5523U. Similar to UC3842, the LD5523U would without voltage offset to feed the voltage divider at the ratio of  $R_A$  and  $R_B$ , that is,

$$V_{-(PWM\_COMPARATOR)} = \frac{R_B}{R_A + R_B} \times V_{COMP}$$

A pull-high resistor is embedded internally and therefore no external one is required.

The LD5523U integrates the multi-mode PWM controller, and for enhance the light load efficiency, the comp pin value corresponding to the frequency is as shown in Fig. 13.

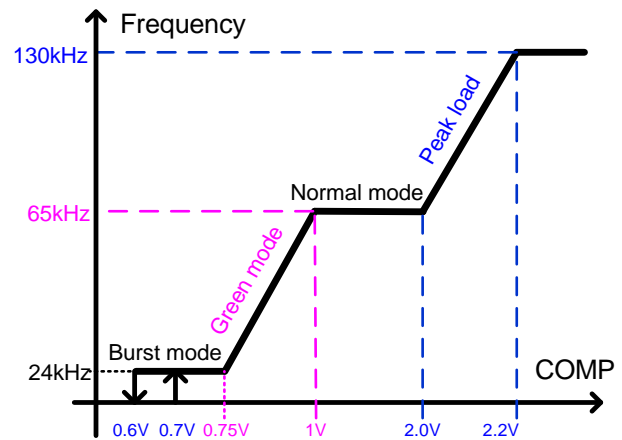


Fig. 13

## Current Sensing, Leading Edge Blanking

The typical current mode of PWM controller feedbacks both current signal and voltage signal to close the control loop and achieve regulation. The LD5523U detect the primary MOSFET current from the CS pin, which is not only for the peak current mode control but also for the pulse-by-pulse current limit. The maximum voltage threshold of the current sensing pin sets at  $0.85V$ . From above, the MOSFET peak current can be obtained from below.

$$I_{PEAK (MAX)} = \frac{0.85V}{R_{CS}}$$

A  $275ns$  leading-edge blanking (LEB) time is included in the input of CS pin to prevent the false-trigger from the current spike. In the low power application, if the total pulse width of the turn-on spike is less than  $275ns$  and the negative spike on the CS pin doesn't exceed  $-0.3V$ , it can remove the R-C filter (as shown in the Fig. 14).

However, the total pulse width of the turn-on spike is decided by the output power, circuit design and PCB layout. It is strongly recommended to adopt a smaller R-C filter (as shown in Fig. 15) for higher power application to avoid the CS pin being damaged by the negative turn-on spike.

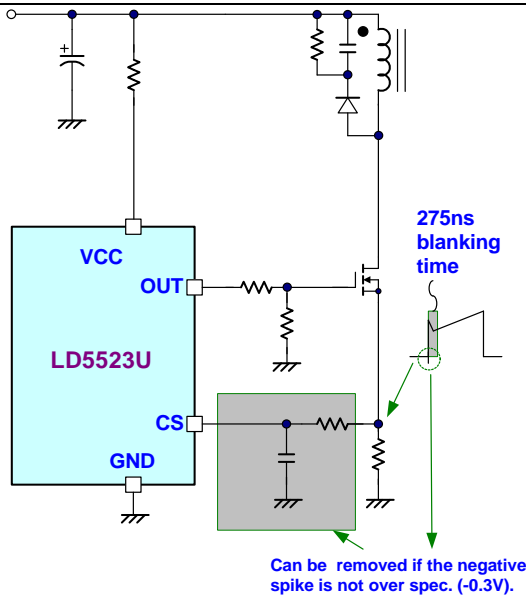


Fig. 14

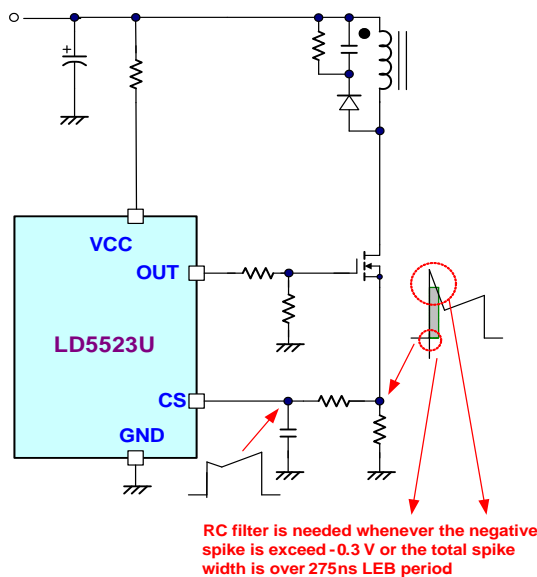


Fig. 15

## Output Stage and Maximum Duty

An output stage of a CMOS buffer, with typical 380mA driving capability, is incorporated to drive a power MOSFET directly. And the maximum duty of LD5523U is limited to 81% avoid detecting QR fail.

## Over Voltage Protection on VCC Pin (VCC OVP) – Auto Recovery

The  $V_{GS}$  ratings of the nowadays power MOSFETs are often limited up to max. 28V. To prevent the  $V_{GS}$  from

the fault condition, LD5523U is implemented with an OVP function on VCC. Whenever the VCC voltage is higher than the OVP threshold voltage, the output gate drive circuit will be shut down simultaneously thus to stop the switching of the power MOSFET until the next UVLO(ON).

The VCC OVP function in LD5523U is an auto-recovery type protection. The Fig. 16 shows its operation.

On the other hand, if the OVP condition is removed, the VCC level will get back to normal level and the output will automatically return to the normal operation.

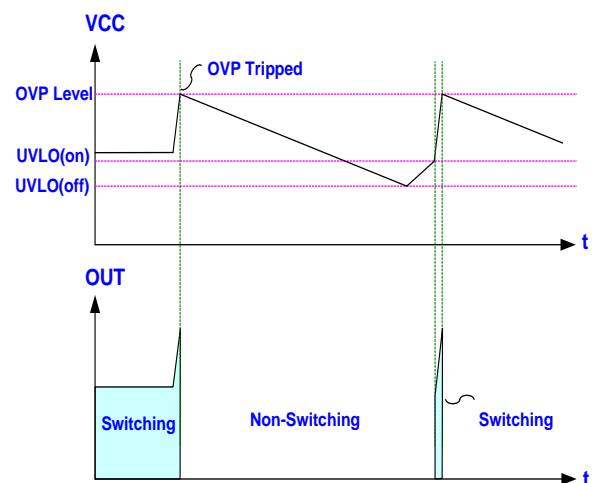


Fig. 16

## Over Power Protection (OPP) – Auto Recovery

To protect the circuit from damage due to over-load condition and short or open-loop condition, the LD5523U is implemented with smart OPP function. LD5523U is auto-recovery function, see Fig. 17 for the waveform. In case of fault condition, the feedback system will force the voltage loop toward the saturation and then pull the voltage high on COMP pin ( $V_{COMP}$ ). When the  $V_{COMP}$  ramps up to the OPP threshold of 2.8V and continues over OPP delay time, the protection will be activated and then turn off the gate output to stop the switching of power circuit.

With the protection mechanism, the average input power will be minimized to remain the component temperature and stress within the safe operating area.

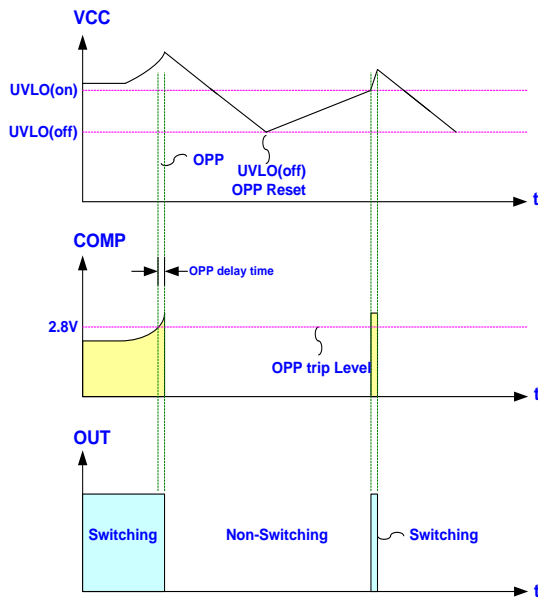


Fig. 17

## Over Current Protection (OCP) – Auto Recovery

When the switching current is higher than the OCP threshold, the internal counter counts down. When the total accumulated counting time is more than 13s, the controller triggers the OCP. This protection for LD5523U is auto recovery.

## Adjustable Over Current Compensation on FB Pin

For compensating the differential input current from high/low line conditions on current sensing resistor, LD5523U mirrors compensation current  $I_{OCP}$  from  $I_{FB}$  to CS pin. The relationship of compensation current  $I_{OCP}$  and  $I_{FB}$  is expressed by following equation and shown in Fig. 18.

$$I_{OCP} = K \times I_{FB}$$

Where  $K = 1.625$

$K$  is the mirror current ratio of FB pin, and the IOCP follows to the input voltage. When the VCOMP ramps up

to the IOCP threshold of 2.4V, the compensation current is added. And the VCOMP hysteresis of IOCP is 0.35V.

The compensation current  $I_{OCP}$  supplies an offset voltage by external resistor  $R_{OCP}$ , which is series between the current sensing resistor  $R_S$  and CS pin. By selecting a proper value of the resistor  $R_{OCP}$  in series with the CS pin, the amount of compensation can be adjusted.

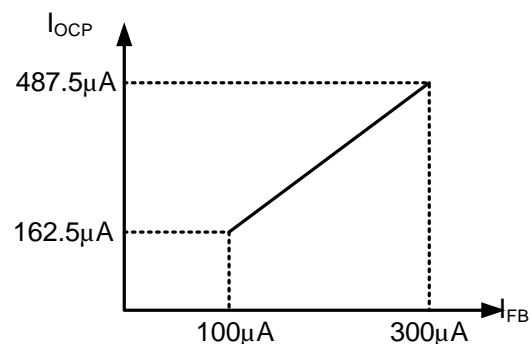


Fig. 18

## Brown-In / Brown-Out Protection (BNI/BNO) – Auto Recovery

The LD5523U integrates the brown in, brownout protection and valley detection into FB pin. The auxiliary voltage reflects a proportional bulk voltage during the on time. Fix the internal current at the BNI and BNO, the BNI level could be set by modulating the FB divided resistors and auxiliary voltage, as shown in Fig. 19. For preventing the abnormal condition of line voltage to causing damage, BNO function is implemented, while turns off the gate signal after de-bounce time 70ms as BNO occurring, as shown in Fig. 20. The relationship of input voltage and BNI/BNO is expressed in following equation.

$$V_{DC\_BNI} = \frac{N_P}{N_a} \cdot I_{BNI} \cdot R_1$$

$$V_{DC\_BNO} = \frac{N_P}{N_a} \cdot I_{BNO} \cdot R_1$$

, where

$V_{DC\_BNI}$  is predicted BNI DC value of input voltage.

$V_{DC\_BNO}$  is predicted BNO DC value of input voltage.

$I_{BNI}$  is BNI trip current.

$I_{BNO}$  is BNO trip current.

$N_p$  is turns ration of primary-side winding.

$N_a$  is turns ration of auxiliary winding.

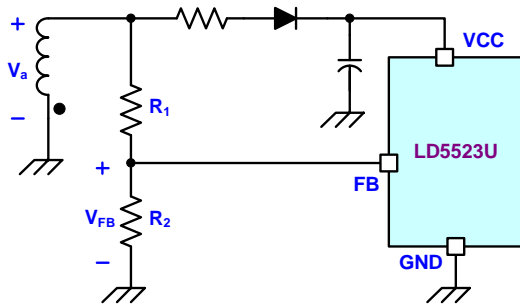


Fig. 19

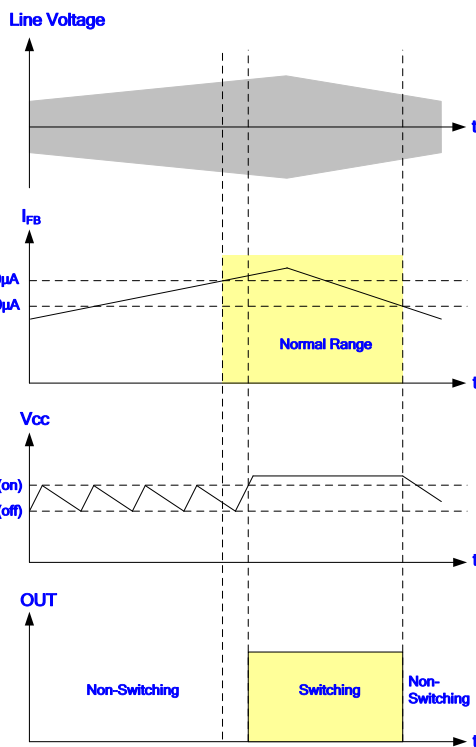


Fig. 20

## Over Voltage Protection on FB Pin (FB OVP) – Auto Recovery

An output overvoltage protection is implemented in the LD5523U. The auxiliary winding voltage can be reflected from secondary winding, in which the FB pin voltage is proportional to output voltage during the gate

off time. OVP is worked by sensing the auxiliary voltage via the divided resistors R2, referring to Fig. 19. The equation of FB OVP is shown as follows.

$$R_2 = \frac{R_1 \cdot V_{FB\_OVP}}{V_a - V_{FB\_OVP}}$$

$$V_a = \frac{N_a}{N_s} (V_o + V_F)$$

$V_{FB\_OVP}$  is the FB pin OVP trip voltage level.  $V_a$  is the auxiliary winding voltage which reflects from the forward voltage  $V_F$  of Schottky diode and output voltage  $V_o$ .  $N_s$  is turns ration of secondary-side winding.

If  $V_{FB}$  overs the FB OVP trip level, the internal counter starts counting 8 cycles, and then LD5523U goes to latch protection mode till VCC pin drops below PDR and starts AC-recycling again.

## Output Short Circuit Protection (OSCP) – Auto Recovery

The OSCP function can prevent the damage from output short circuit. Once the output is shorted,  $V_o$  and  $V_{CC}$  drop immediately, which always reflects the auxiliary winding during the gate off region. Therefore, as  $V_{FB}$  is lower than 0.8V during gate off region, then the  $FB\_UVP$  is triggered, and skips one cycle. According to the close loop control, COMP voltage will pull high in the meanwhile. If the VCOMP pulls higher than 2.8V over 13ms and  $V_{CC}$  drops below 9.6V. At this time, the OSCP protection will be triggered and turn off the gate driving.

## Over Temperature Protection on CS Pin (CS OTP) – Auto Recovery

LD5523U is implemented over temperature protection on CS pin which senses voltage to determine NTC status during gate off region. As  $V_{CS}$  is greater than 0.75V and continues for 5.4ms,  $CS\_OTP$  is triggered, then LD5523U is in auto recovery mode till the temperature drops to setting work condition.

## Oscillator and Switching Frequency

The LD5523U is implemented with frequency swapping function which helps the power supply designers to both optimize EMI performance and lower system cost.

## Secondary Diode Short Protection (SDSP) – Auto Recovery

The method that the LD5523U judges the logic of SDSP is described briefly as follows. When VCS is higher than 1.5V, it will reduce the frequency first, even the  $T_{on} < LEB + T_{PD}$ . When the count is up to 4 times, its gate will be turned-off, shown as Fig. 21.

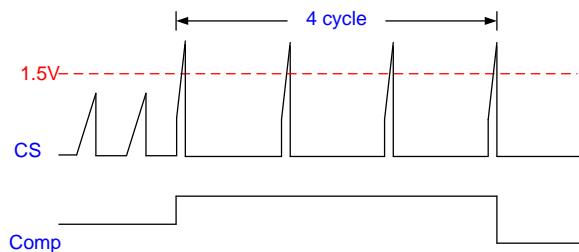


Fig. 21

## Green Mode Operation

By using the green-mode control, the switching frequency can be reduced under the light load condition. This feature helps to improve the efficiency in light load conditions. The green-mode control is Leadtrend Technology's own property.

## Fault Protection

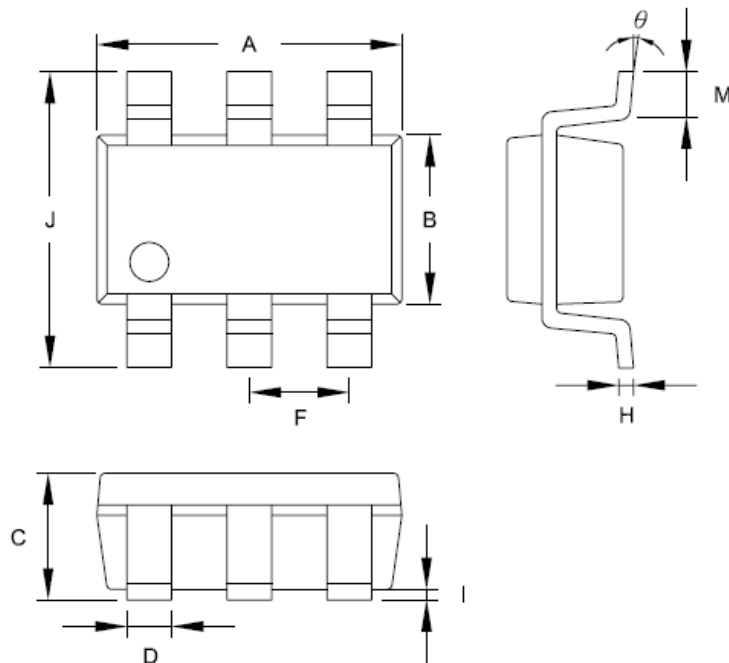
There are several critical protections integrated in the LD5523U to prevent from damage to the power supply. Those damages usually come from open or short conditions on the pins of LD5523U.

In case under such conditions listed below, the gate output will turn off immediately to protect the power circuit.

1. CS pin floating
2. COMP pin floating

## Package Information

SOT-26



Symbol	Dimension in Millimeters		Dimensions in Inches	
	Min	Max	Min	Max
A	2.692	3.099	0.106	0.122
B	1.397	1.803	0.055	0.071
C	-----	1.450	-----	0.057
D	0.300	0.500	0.012	0.020
F	0.95 TYP		0.037 TYP	
H	0.080	0.254	0.003	0.010
I	0.050	0.150	0.002	0.006
J	2.600	3.000	0.102	0.118
M	0.300	0.600	0.012	0.024
θ	0°	10°	0°	10°



**Revision History**

REV.	Date	Change Notice
00	11/12/2020	Original Specification

**Important Notice**

Leadtrend Technology Corp. reserves the right to make changes or corrections to its products at any time without notice.  
Customers should verify the datasheets are current and complete before placing order.